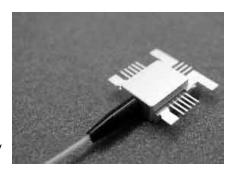


#### SUMITOMO ELECTRIC INDUSTRIES, LTD.

## **Preliminary**

#### Features

- · Bit rate: ~10Gb/s
- · Power supply: +3.3V/-5.2V
- Packaging: small size and high performance butterfly package
- · Light wavelength:1.31μm/1.55μm
- · Optical pigtail: 9µm/125µm SM fiber
- · Back-illuminated GaInAs/InP pin-photodiode with monolithic lens
- · Low noise preamplifier IC
- · High sensitivity: ~-19dBm
- · Differential output



#### **Applications**

· High-speed optical transmission systems for OC-192/STM-64 (10Gb/s) and measurement instruments

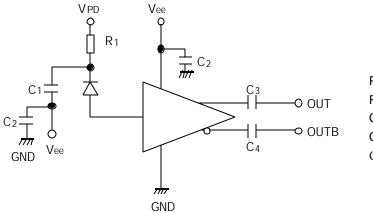
#### Functional Description

This PIN-preamplifier module is a low-cost capable receiver module with a miniature size for use in the 10Gb/s SONET/SDH systems. A Back-illuminated pin-photodiode has a monolithic lens optimized for SM fiber at the InP substrate and achieves high responsivity, wide-tolerance and high-speed. The component of a high-speed and low-noise preamplifier and the photodiode obtains high sensitivity and a stable operation. The high performance butterfly package was developed for a high-speed operation, small dimension and low cost.

The module is applicable for  $1.31\mu\text{m}/1.55\mu\text{m}$  optical fiber communication systems for OC-192/STM-64, typically showing a high sensitivity of -19dBm.

## Block Diagram

## **Preliminary**



PD diameter: 30μmφ

R 1=50Ω C 1=100pF C 2=400pF

. C3=C4=0.1μF

## Absolute Maximum Ratings

Parameter	Symbol	Min.	Max.	Unit
Power Supply	VPD	0	+10	V
Power Supply	Vee	-6	+0.5	V
Maximum Optical Input Power	Pin	-	+3	dBm
Operating Temperature	Ta	-40	+85	deg
Storage Temperature	Tstg	-40	+85	deg

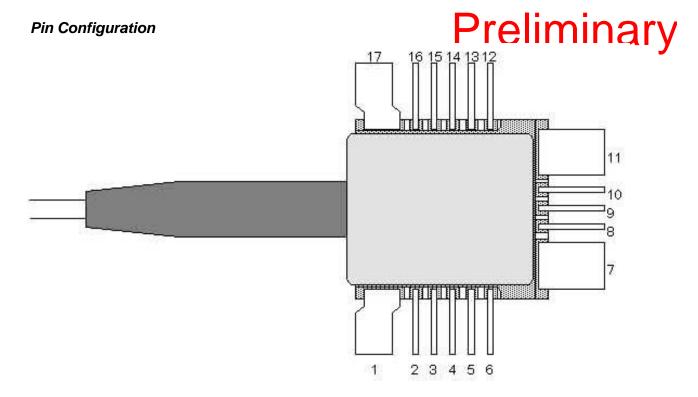
## **Recommended Operating Conditions**

Parameter	Symbol	Min.	Тур.	Max.	Unit
Power Supply	VPD	3.1	+3.3	+5.25	V
Power Supply	Vee	-5.5	-5.2	-4.9	V
Operating Temperature	Ta	-40	25	+85	deg

#### **Electrical Characteristics**

# **Preliminary**

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Supply Current	Iss		-	70	90	m A
Optical Return Loss	ORL	λ=1.31/1.55μm	-	-35	-27	dB
Optical Wavelength	λ		1290	-	1565	nm
Responsivity	R <sub>1310</sub>	λ=1.31μm, Vpd=3.3V	0.7	0.9	•	AW
	R <sub>1550</sub>	λ=1.55μm, Vpd=3.3V	0.8	1.0	-	AW
Transimpedance	<b>Z</b> t	f=1GHz, single-ended	550	700	825	Ω
Bandwidth	BW-3dB	3dB down	7.5	10	-	GHz
Low frequency –3dB Cutoff	BWLF	3dB down	-	25	40	kHz
Input Noise Current Density	Inoise		-	TBD	-	pA√ Hz
Sensitivity	Pinmin	λ=1.55μm, Vpd=3.3V	-	-19	-14	dBm
Overload	Pinmax	λ=1.55μm, Vpd=3.3V	0	1	-	dBm
Output Return Loss	S22	f=100MHz-7GHz	-	-10	9	dB



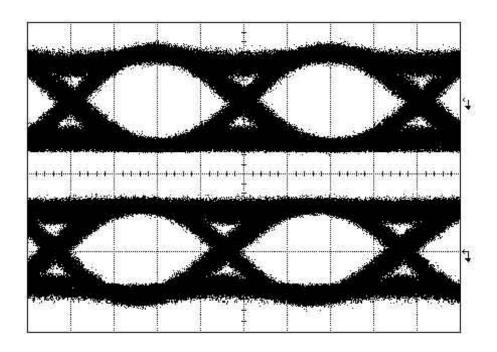
### **Connection Table**

No.	Symbol	Parameter	No.	Symbol	Parameter
1	GND	Ground (0.0V)	10	OUT	Positive Output
2	VPD	Power Supply (+3.3V)	11	GND	Ground (0.0V)
3	NC	No Connection	12	GND	Ground (0.0V)
4	Vee	Power Supply (-5.2V)	13	NC	No Connection
5	NC	No Connection	14	NC	No Connection
6	GND	Ground (0.0V)	15	NC	No Connection
7	GND	Ground (0.0V)	16	NC	No Connection
8	OUTB	Negative Output	17	GND	Ground (0.0V)
9	GND	Ground (0.0V)			

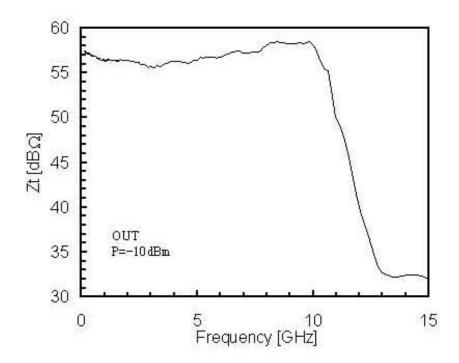
### Typical AC Characteristics

## **Preliminary**

(1) Eye Diagrams (Ta=25deg,  $50\Omega$  load) Average Optical Input Power: -14dBm( $\lambda$ =1.55 $\mu$ m, 9.95328Gb/s, NRZ, PRBS2<sup>31</sup>-1)

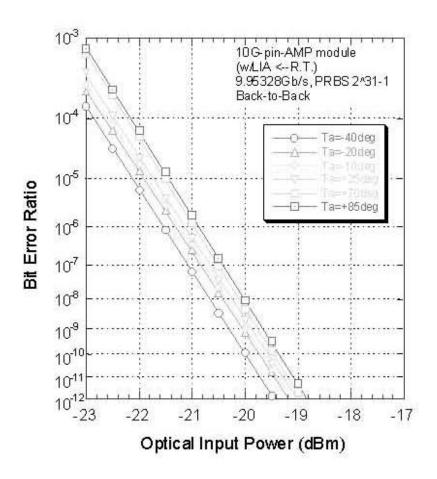


(2) Frequency Response ( $\lambda$ =1.31 $\mu$ m) Average Optical Input Power: -10dBm



(3) Bit Error Rate Curve ( $\lambda$ =1.55 $\mu$ m, 9.95328Gb/s, NRZ, PRBS2<sup>31</sup>-1)

## **Preliminary**



Packaging

# **Preliminary**

